

G-æniel Bond – Application mode

Selective etch approach (unground enamel)



Apply phosphoric acid on enamel surfaces only for 10s



Rinse thoroughly for 5s



Dry thoroughly for 5s

At this stage, follow the same steps of self-etch approach



Apply G-æniel Bond on tooth surface



Leave undisturbed for 10s after application



Dry thoroughly for 5s under maximum air pressure



Light cure for 10s